

Thyristor Module

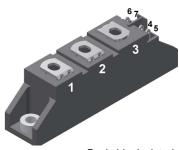
 $V_{RRM} = 2x 1800 V$

 $I_{TAV} = 110 A$

 $V_T = 1.21 V$

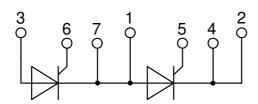
Part number

MCMA110P1800TA



Backside: isolated





Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converterAC power control
- Lighting and temperature control

Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

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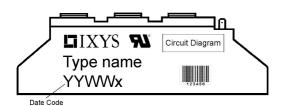


Thyristo	r				Ratings	5	
Symbol	Definition	Conditions		min.	typ.	max.	Uni
V _{RSM/DSM}	max. non-repetitive reverse/forwa	rd blocking voltage	$T_{VJ} = 25^{\circ}C$			1900	١
V _{RRM/DRM}	max. repetitive reverse/forward bl	ocking voltage	$T_{VJ} = 25^{\circ}C$			1800	١
I _{R/D}	reverse current, drain current	V _{R/D} = 1800 V	$T_{VJ} = 25^{\circ}C$			100	μ
		$V_{R/D} = 1800 \text{ V}$	$T_{VJ} = 140^{\circ}C$			10	m
V _T	forward voltage drop	I _T = 110 A	$T_{VJ} = 25^{\circ}C$			1.24	'
		$I_T = 220 A$				1.52	,
		$I_T = 110 A$	$T_{VJ} = 125$ °C			1.21	,
		I _⊤ = 220 A				1.57	,
I _{TAV}	average forward current	$T_{c} = 85^{\circ}C$	$T_{VJ} = 140$ °C			110	
T(RMS)	RMS forward current	180° sine				170	,
V_{T0}	threshold voltage } for power la	oss calculation only	$T_{VJ} = 140$ °C			0.85	١
r _T	slope resistance	oss calculation only				3.3	m۵
R _{thJC}	thermal resistance junction to cas					0.3	K/V
R _{thCH}	thermal resistance case to heatsi	nk			0.2		K/V
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			380	٧
I _{TSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			1.90	k,
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			2.05	k,
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 140$ °C			1.62	k,
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.75	k.
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			18.1	kA ²
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			17.5	kA ²
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 140$ °C			13.0	kA ²
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			12.7	kA ²
C ¹	junction capacitance	$V_R = 400 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		95		р
P_{GM}	max. gate power dissipation	$t_P = 30 \mu s$	$T_{C} = 140^{\circ}C$			10	۷
_		$t_{P} = 300 \mu s$				5	۷
P _{GAV}	average gate power dissipation					0.5	V
(di/dt) _{cr}	critical rate of rise of current	•	epetitive, $I_T = 330 \text{ A}$			150	A/μ
		$t_P = 200 \mu\text{s}; di_G/dt = 0.45 A/\mu\text{s}; -$					
			on-repet., $I_{T} = 110 \text{ A}$			500	<u> </u>
(dv/dt) _{cr}	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140$ °C			1000	V/μ
.,		R _{GK} = ∞; method 1 (linear volta	-			4.5	!
V _{GT}	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			1.5	,
			$T_{VJ} = -40$ °C			1.6	<u> </u>
I _{GT}	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			150	m
.,		V 2/V	$T_{VJ} = -40$ °C			200	m/
V _{GD}	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^{\circ}C$			0.2	,
I _{GD}	gate non-trigger current		T 0500			10	m
I _L	latching current	$t_p = 10 \mu s$	$T_{VJ} = 25 ^{\circ}C$			200	m
	haddle a sumant	$I_{\rm G} = 0.45 \text{A}; \text{di}_{\rm G}/\text{dt} = 0.45 \text{A}/\mu \text{s}$				000	
I _H	holding current	$V_D = 6 V R_{GK} = \infty$	$T_{VJ} = 25^{\circ}C$			200	m,
t _{gd}	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25 ^{\circ}\text{C}$			2	μ
	A aff time a	$I_{\rm G} = 0.45 \text{A}; \text{di}_{\rm G}/\text{dt} = 0.45 \text{A}/\mu \text{s}$			40-		
t _q	turn-off time	$V_R = 100 \text{ V}; I_T = 110 \text{A}; V = \frac{2}{3}$	$^{\prime}$ 3 V _{DRM} I _{VJ} = 125 °C		185		μ



MCMA110P1800TA

Package	Package TO-240AA			Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					200	Α
T _{VJ}	virtual junction temperature	е			-40		140	°C
T _{op}	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		125	°C
Weight						81		g
M _D	mounting torque				2.5		4	Nm
$\mathbf{M}_{_{T}}$	terminal torque				2.5		4	Nm
d _{Spp/App}		ace striking distance through air	terminal to terminal	13.0	9.7			mm
d _{Spb/Apb}	creepage distance on sun	ace striking distance through an	terminal to backside	16.0	16.0			mm
V _{ISOL}	isolation voltage	t = 1 second			4800			٧
1002	t = 1 minut		50/60 Hz, RMS; IISOL ≤ 1 mA		4000			٧



Part description

M = Module
C = Thyristor (SCR)
M = Thyristor

A = (up to 1800V) 110 = Current Rating [A] P = Phase leg

1800 = Reverse Voltage [V]

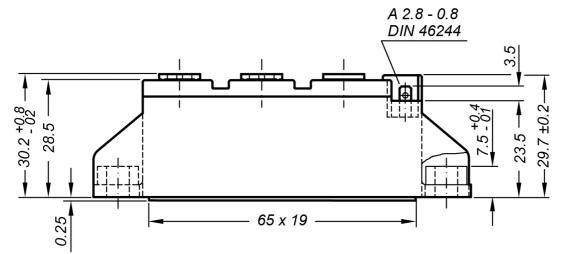
TA = TO-240AA-1B

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA110P1800TA	MCMA110P1800TA	Box	36	524642

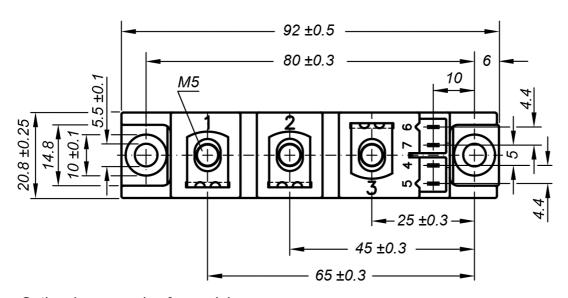
Equiva	lent Circuits for	Simulation	* on die level	$T_{VJ} = 140^{\circ}C$
$I \rightarrow V_0$)—[R _o]-	Thyristor		
V _{0 max}	threshold voltage	0.85		V
$R_{0 max}$	slope resistance *	2.1		$m\Omega$



Outlines TO-240AA



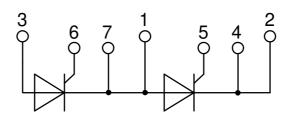
General tolerance: DIN ISO 2768 class "c"



Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red Type $\frac{7}{200}$ (L = Left for pin pair $\frac{4}{5}$)

Type ZY 200L (L = Left for pin pair 4/5) Type ZY 200R (R = Right for pin pair 6/7) UL 758, style 3751







Thyristor

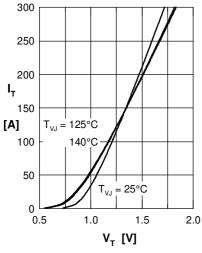


Fig. 1 Forward characteristics

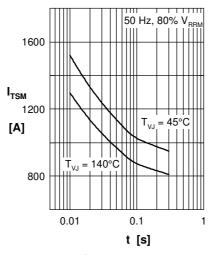


Fig. 2 Surge overload current I_{TSM} : crest value, t: duration

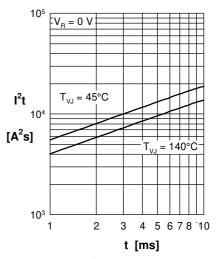


Fig. 3 I²t versus time (1-10 s)

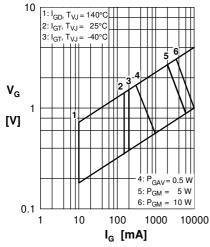


Fig. 4 Gate voltage & gate current

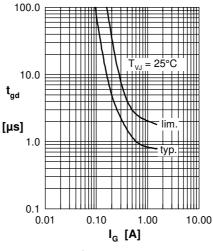


Fig. 5 Gate controlled delay time t_{ad}

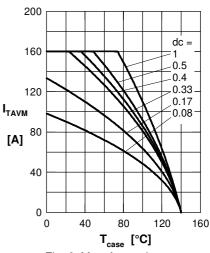


Fig. 6 Max. forward current at case temperature

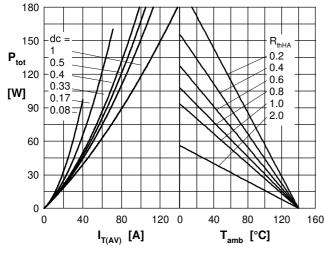


Fig. 7a Power dissipation versus direct output current Fig. 7b and ambient temperature

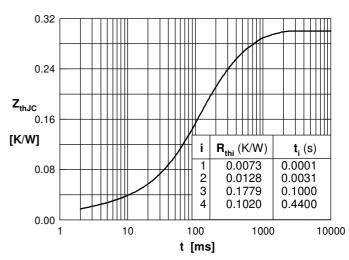


Fig. 8 Transient thermal impedance junction to case

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T2001N34TOF T901N35TOF T1080N02TOF T360N22TOF TZ810N22KOF T420N18TOF T420N14TOF TD305N16KOF T740N26TOF
T360N24TOF T430N16TOF T300N16TOF TD520N22KOF TT305N16KOF TT270N16KOF TD600N16KOF T740N22TOF T640N12TOF
T470N12TOF NTE5728 ETZ1100N16P70HPSA1 T430N18TOF TD700N22KOFHPSA1 T3441N52TOH T2851N48TOH
TD820N16KOFHPSA1 MCD501-16IO2 MCD501-18IO2 SK 100 KQ 12 SK 45 UT 16 SKKT 106B12 E SKKT 27/16E VSST180S12P0VPBF PSET132/16